



Vishay Semiconductors

Optocoupler, Phototransistor Output, SOP-6L5, Half Pitch, Long Mini-Flat Package

Features

- SMD Low profile 5 pin package
- Isolation Test Voltage 5000 V_{RMS}
- CTR flexibility available see order information
- Special construction
- Extra low coupling capacitance
- Connected base
- DC input with transistor output
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

Agency Approvals

- UL1577, File No. E76222 System Code W, Double Protection
- CSA 22.2 Bulletin 5A
- BSI IEC60950 IEC60065
- DIN EN 60747-5-2 (VDE0884) DIN EN 60747-5-5 pending
- FIMKO
- NOTE:
 - See the Safety Standard Approval List "Agency Table" for more detailed information.

Applications

Switchmode power supplies Computer peripheral interface Microprocessor system interface



Description

The TCLT11.. Series consists of a phototransistor optically coupled to a gallium arsenide infrared-emitting diode in a 5-lead SOP-6L package.

The elements are mounted on one leadframe providing a fixed distance between input and output for highest safety requirements.

Order Information

Part	Remarks
TCLT1100	CTR 50 - 600 %, SOP-6L5
TCLT1102	CTR 63 - 125 %, SOP-6L5
TCLT1103	CTR 100 - 200 %, SOP-6L5
TCLT1104	CTR 160 - 320 %, SOP-6L5
TCLT1105	CTR 50 - 150 %, SOP-6L5
TCLT1106	CTR 100 - 300 %, SOP-6L5
TCLT1107	CTR 80 - 160 %, SOP-6L5
TCLT1108	CTR 130 - 260 %, SOP-6L5
TCLT1109	CTR 200 - 400 %, SOP-6L5

NOTE: Available only on tape and reel.

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Absolute Maximum Ratings

 T_{amb} = 25 °C, unless otherwise specified

Stresses in excess of the absolute Maximum Ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute Maximum Rating for extended periods of the time can adversely affect reliability.

Input

Parameter	Test condition	Symbol	Value	Unit
Reverse voltage		V _R	6	V
Forward current		١ _F	60	mA
Forward surge current	$t_p \le 10 \ \mu s$	I _{FSM}	1.5	A
Power dissipation		P _{diss}	100	mW
Junction temperature		Tj	125	°C

Output

Parameter	Test condition	Symbol	Value	Unit
Collector emitter voltage		V _{CEO}	70	V
Emitter collector voltage		V _{ECO}	7	V
Collector current		Ι _C	50	mA
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I _{CM}	100	mA
Power dissipation		P _{diss}	150	mW
Junction temperature		Тj	125	°C

Coupler

Parameter	Test condition	Symbol	Value	Unit
Isolation test voltage (RMS)		V _{ISO}	5000	V _{RMS}
Total power dissipation		P _{tot}	250	mW
Operating ambient temperature range		T _{amb}	- 40 to + 100	°C
Storage temperature range		T _{stg}	- 40 to + 100	°C
Soldering temperature		T _{sld}	260	°C

Electrical Characteristics

 $T_{amb} = 25 \ ^{\circ}C$, unless otherwise specified

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

Input

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Forward voltage	$I_F = \pm 50 \text{ mA}$	V _F		1.25	1.6	V
Junction capacitance	V _R = 0 V, f = 1 MHz	Cj		50		pF

Output

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Collector emitter voltage	I _C = 1 mA	V _{CEO}	70			V
Emitter collector voltage	I _E = 100 μA	V _{ECO}	7			V
Collector-emitter cut-off current	$V_{CE} = 20 \text{ V}, I_{f} = 0, E = 0$	I _{CEO}		10	100	nA

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Coupler

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Collector emitter saturation voltage	$I_{\rm F} = 10$ mA, $I_{\rm C} = 1$ mA	V _{CEsat}			0.3	V
Cut-off frequency	$V_{CE} = 5 \text{ V}, \text{ I}_{F} = 10 \text{ mA},$ $R_{L} = 100 \Omega$	f _c		110		kHz
Coupling capacitance	f = 1 MHz	C _k		0.3		pF

Current Transfer Ratio

Parameter	Test condition	Part	Symbol	Min	Тур.	Max	Unit
I _C /I _F	$V_{CE} = 5 \text{ V}, I_{F} = 5 \text{ mA}$	TCLT1100	CTR	50		600	%
	V _{CE} = 5 V, I _F = 10 mA	TCLT1102	CTR	63		125	%
		TCLT1103	CTR	100		200	%
		TCLT1104	CTR	160		320	%
	$V_{CE} = 5 \text{ V}, I_{F} = 1 \text{ mA}$	TCLT1102	CTR	22	45		%
		TCLT1103	CTR	34	70		%
		TCLT1104	CTR	56	100		%
	$V_{CE} = 5 V, I_{F} = 5 mA$	TCLT1105	CTR	50		150	%
		TCLT1106	CTR	100		300	%
		TCLT1107	CTR	80		160	%
		TCLT1108	CTR	130		260	%
		TCLT1109	CTR	200		400	%

Maximum Safety Ratings

(according to DIN EN 60747-5-2(VDE0884)/ DIN EN 60747-5-5 pending) see figure 1 This optocoupler is suitable for safe electrical isolation only within the safety ratings.

Compliance with the safety ratings shall be ensured by means of suitable protective circuits.

Input

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Forward current		۱ _F			130	mA

Output

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Power dissipation		P _{diss}			265	mW

Coupler

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Rated impulse voltage		V _{IOTM}			8	kV
Safety temperature		T _{si}			150	°C

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Insulation Rated Parameters

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Partial discharge test voltage - Routine test	100 %, t _{test} = 1 s	V _{pd}	1.6			kV
Partial discharge test voltage - Lot test (sample test)	$t_{Tr} = 60 \text{ s}, t_{test} = 10 \text{ s},$ (see figure 2)	V _{IOTM}	8			kV
		V _{pd}	1.3			kV
Insulation resistance	V _{IO} = 500 V	R _{IO}	10 ¹²			Ω
	V_{IO} = 500 V, T_{amb} = 100 °C	R _{IO}	10 ¹¹			Ω
	V_{IO} = 500 V, T_{amb} = 150 °C	R _{IO}	10 ⁹			Ω
	(construction test only)					



Figure 1. Derating diagram



Figure 2. Test pulse diagram for sample test according to DIN EN 60747-5-2(VDE0884)/ DIN EN 60747-; IEC60747





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Switching Characteristics

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Delay time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega$ (see figure 3)	t _d		3.0		μs
Rise time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega$ (see figure 3)	t _r		3.0		μs
Turn-on time	$V_{S} = 5 \text{ V}, I_{C} = 2 \text{ mA}, R_{L} = 100 \Omega$ (see figure 3)	t _{on}		6.0		μs
Storage time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega$ (see figure 3)	t _s		0.3		μs
Fall time	$V_{S} = 5 \text{ V}, \text{ I}_{C} = 2 \text{ mA}, \text{ R}_{L} = 100 \Omega$ (see figure 3)	t _f		4.7		μs
Turn-off time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega$ (see figure 3)	t _{off}		5.0		μs
Turn-on time	$V_S = 5 \text{ V}, I_F = 10 \text{ mA}, R_L = 1 \text{ k}\Omega$ (see figure 4)	t _{on}		9.0		μs
Turn-off time	$V_S = 5 \text{ V}, I_F = 10 \text{ mA}, R_L = 1 \text{ k}\Omega$ (see figure 4)	t _{off}		10.0		μs





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Figure 5. Switching Times



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Figure 4. Test circuit, saturated operation

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Typical Characteristics (Tamb = 25 °C unless otherwise specified)



Figure 6. Total Power Dissipation vs. Ambient Temperature



Figure 7. Forward Current vs. Forward Voltage







Figure 9. Collector Dark Current vs. Ambient Temperature



Figure 10. Collector Current vs. Forward Current



Figure 11. Collector Current vs. Collector Emitter Voltage



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Figure 12. Collector Emitter Saturation Voltage vs. Collector Current



Figure 13. Current Transfer Ratio vs. Forward Current



Figure 14. Turn on / off Time vs. Collector Current



Figure 15. Turn on / off Time vs. Forward Current

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Package Dimensions in mm







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Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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